Vishay Semiconductors

Hyperfast Rectifier, 16 A FRED Pt®



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LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	16 A				
V _R	600 V				
V _F at I _F (T _J = 150 °C)	1.24 V				
t _{rr}	30 ns				
T _J max.	175 °C				
Package	SMPD (TO-263AC)				
Circuit configuration	Single				

FEATURES

Hyperfast recovery time, reduced Q_{rr}, and soft recovery



COMPLIANT HALOGEN

FREE

- 175 °C maximum operating junction temperature
- For PFC CRM, snubber operation
- · Low forward voltage drop
- · Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, lighting, in the AC/DC section of SMPS, freewheeling and clamp diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

MECHANICAL DATA

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Peak repetitive reverse voltage	V _{RRM}		600	V			
Average rectified forward current	I _{F(AV)} ⁽¹⁾	T _C = 127 °C	16	٨			
Non-repetitive peak surge current	I _{FSM}	$T_J = 25 \text{ °C}, 10 \text{ ms sine pulse}$ 160		A			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V_{BR}, V_{R}	I _R = 100 μA	600	-	-	
Family alterna	V _F	I _F = 16 A	-	1.65	2.15	V
Forward voltage		I _F = 16 A, T _J = 150 °C	-	1.24	1.65	
Reverse leakage current	I _R	$V_{R} = V_{R}$ rated	-	-	20	
neverse leakage current		$T_J = 150 \ ^{\circ}C$, $V_R = V_R$ rated	-	-	500	μΑ
Junction capacitance	CT	V _R = 600 V	-	16	-	pF

Note

⁽¹⁾ Mounted on infinite heatsink

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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
			/μs, V _R = 30 V	-	30	-	
Boyoroo rocoyory timo	+	I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A		-	-	30	
Reverse recovery time	t _{rr}	T _J = 25 °C		-	43	-	- ns
		T _J = 125 °C		-	92	-	
Deels receivers everent		T _J = 25 °C	l _F = 16 A, dl _F /dt = 500 A/µs,	-	7.7	-	А
Peak recovery current	IRRM	T _J = 125 °C	$V_{\rm B} = 400 \text{ V}$	-	13.8	-	A
Bayaraa raaayany aharaa	0	T _J = 25 °C		-	150	-	μC
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	600	-	μΟ

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	+175	°C	
Thermal resistance, junction to mount	R _{thJM}		-	1.2	1.7	°C/W	
Approximate weight				0.55		g	
Marking device		Case style SMPD (TO-263AC)		16EI	DH06		

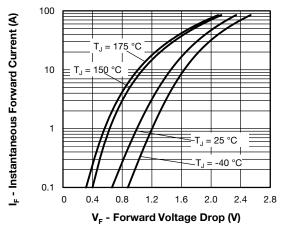


Fig. 1 - Typical Forward Voltage Drop Characteristics

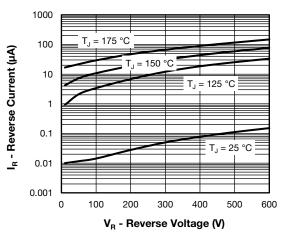


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

VS-16EDH06-M3

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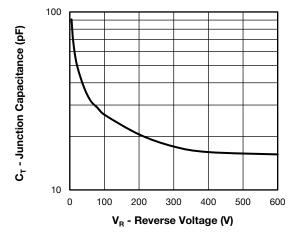


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

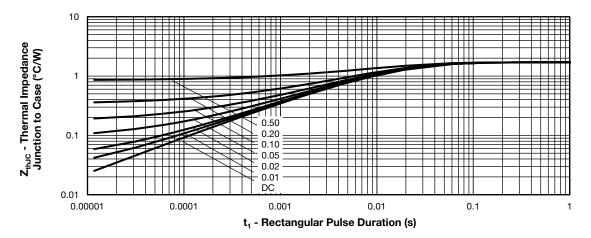
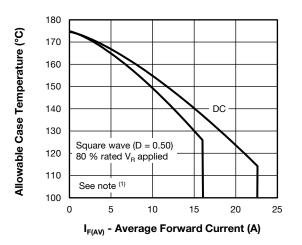
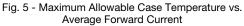


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics





Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{5}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

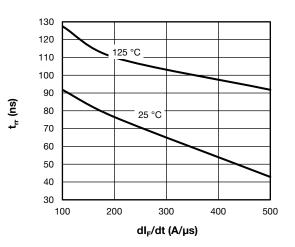


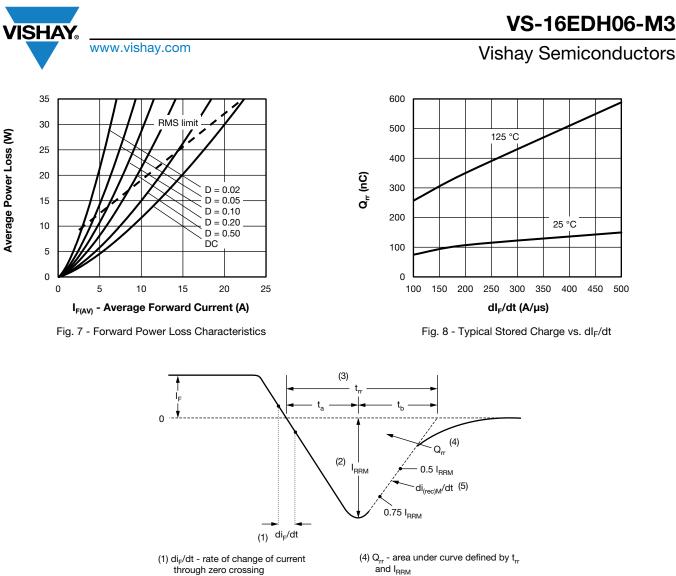
Fig. 6 - Typical Reverse Recovery Time vs. dl_F/dt

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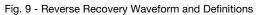
(2) I_{RRM} - peak reverse recovery current

(3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.

and I_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) di_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}





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ORDERING INFORMATION TABLE

Device code	VS-	16	E	D	н	06	-M3
	1	2	3	4	5	6	7
	1	- Visł	nay Sem	nicondu	ctors pr	oduct	
	2	- Cur	rent rati	ng (16 A	A)		
	3	- Circ	cuit cont	figuratio	n:		
		E =	single c	lie			
	4	- D=	SMPD	package	Э		
	5	- Pro	cess typ	be,			
		H =	hyperfa	ast recov	/ery		
	6	- Volt	tage coo	de (06 =	600 V)		
	7	M3	B = halog	gen-free	, RoHS	-compl	iant, and

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER REEL MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-16EDH06-M3/I	2000	2000	13" diameter plastic tape and reel				

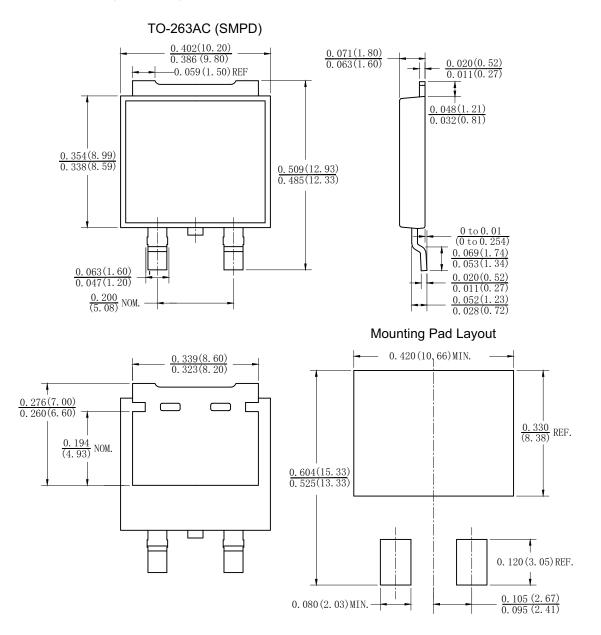
LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95604					
Part marking information	www.vishay.com/doc?95566				
Packaging information	www.vishay.com/doc?88869				





TO-263AC (SMPD)

DIMENSIONS in inches (millimeters)





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